



PAM8904E

### **18VPP OUTPUT PIEZO SOUNDER DRIVER**

## Description

The PAM8904E is a piezo sounder driver with integrated charge pump boost converter. The PAM8904E is capable of driving a ceramic/piezo sounder with  $27V_{PP}$  from a 4.5V power supply. The charge pump can operate in either 1x, 2x or 3x mode.

The boost converter operates at a fixed frequency of 100kHz and provides a 3X  $V_{IN}$  output with a minimum number of external components. The PAM8904E can drive up to 47nF loading. Diodes Incorporated's unique drive technology provides a small inrush current, low EMI and high efficiency.

The PAM8904E includes built-in automatic shutdown and wake up that guarantees longer battery life. The PAM8904E features thermal shutdown, over current protection, over voltage protection and under voltage lock-out.

The PAM8904E is available in U-QFN3030-16 (Type B), U-QFN3030-12 (Type A) and W-QFN2020-12 (Type US) packages.

## Features

- Supply Voltage Range from 1.5V to 5.5V
- 18V<sub>PP</sub> Output from a 3V Supply
- Integrated Boost Converter Generates up to 13.5V Supply
- Input Signal 20Hz to 300kHz
- No Voltage Cross Output in Shutdown Mode
- Low Current Consumption
- Automatic Standby and Wake-up Control
- Available in Space Saving Packages U-QFN3030-16 (Type B), U-QFN3030-12 (Type A) and W-QFN2020-12 (Type US) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

### **Pin Assignments**



U-QFN3030-12 (Type A)/W-QFN2020-12 (Type US)



# Applications

- Health care systems
- Alarm clocks
- Security devices
- Home appliances

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



# **Typical Applications Circuit**



# **Pin Descriptions**

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Pin N	lumber			
U-QFN3030-16 (Type B)	U-QFN3030-12 (Type A)/ W-QFN2020-12 (Type US)	Pin Name	I/O/P	Function
1	1	EN1	I	Charge Pump Mode Select 1
2	2	EN2	<u> </u>	Charge Pump Mode Select 2
3	3	DIN	I	Signal Input
4		NC		No Connection
5	4	CN1	I	Capacitor 1 Negative Terminal
6	5	GND	P	Ground
7	6	VO2	0	Positive Output
8		NC		No Connection
9	7	VO1	0	Negative Output
10	8	CN2		Capacitor 2 Negative Terminal
11	9	CP1	I	Capacitor 1 Positive Terminal
12		NC		No Connection
13	10	VOUT	0	Boost Output
14	11	CP2	I	Capacitor 2 Positive Terminal
15	12	VIN	Р	Power Supply
16	_	NC	—	No Connection



# Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Symbol	Characteristics	Value	Unit
VIN	Supply Voltage	-0.3 to 6.0	V
Vout	Output Voltage	15	V
Ven1, Ven2	EN1, EN2 Voltage	GND -0.3 to V <sub>IN</sub> +0.3	V
T <sub>A</sub>	Operating Free-Air Temperature Range	-40 to +85	°C
TJ	Operating Junction Temperature Range	-40 to +150	°C
Tstg	Storage Temperature Range	-65 to +150	°C

# Recommended Operating Conditions (@TA = +25°C, unless otherwise specified.)

Symbol	Characteristics		Min	Max	Unit
Vin	Supply Voltage	—	1.5	5.5	V
V <sub>IH</sub>	High-Level Input Voltage	EN1, EN2	1.2 to V <sub>IN</sub> +0.3		V
V <sub>IL</sub>	Low-Level Input Voltage	EN1, EN2	-0.3	0.4	V
T <sub>A</sub>	Operating Free-Air Temperature		-40	+85	°C

# Thermal Information

Symbol	Parameter	Package	Max	Unit
	θJA Thermal Resistance (Junction to Ambient)	U-QFN3030-16 (Type B)	35	
θја		U-QFN3030-12 (Type A)	35	°C/W
		W-QFN2020-12 (Type US)	68	
		U-QFN3030-16 (Type B)	14	
θις	Thermal Resistance (Junction to Case)	U-QFN3030-12 (Type A)	14	°C/W
		W-QFN2020-12 (Type US)	25	



Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Vout	Output Voltage Range	(Note 4)	1.5	—	13.5	V
Vout1		1x Mode	2.8	—	3	V
Vout2		2x Mode	5.2	—	6	V
Vout3	Output Voltage	3x Mode (Note 5)	7.2	—	9	V
Vout4		3x Mode (V <sub>IN</sub> = 2.7V)	6.8	7	8.0	V
I <sub>DD11</sub>		1x Mode, C <sub>PIEZO</sub> = No Load	_	43	—	μA
IDD12	Operating Current 1	2x Mode, CPIEZO = No Load	_	118	—	μA
I <sub>DD13</sub>		3x Mode, C <sub>PIEZO</sub> = No Load	_	220	—	μA
I <sub>DD21</sub>		1x Mode, Single-Ended Application	_	0.48	_	mA
IDD22	Operating Current 2	2x Mode, Single-Ended Application	_	1.9	—	mA
IDD23	]	3x Mode, Single-Ended Application	_	4.3	—	mA
IDD31		1x Mode, Differential Application	_	1.7	—	mA
IDD32	Operating Current 3	2x Mode, Differential Application	_	6.4	—	mA
IDD33		3x Mode, Differential Application	_	14.2	—	mA
Isp	Shutdown Current	DIN = 0V	_	0.008	1	μA
fın	Input Frequency	Rectangular Pulse	_	3.2	—	kHz
fosc	Oscillating Frequency	—	70	100	130	kHz
ton1		1x Mode, From DIN Signal High to 90% V <sub>OUT</sub> Steady State	_	470	—	μs
t <sub>ON2</sub>	VOUT Start Delay Time	2x Mode, From DIN Signal High to 90% VOUT Steady State	_	1.76	_	ms
tоnз		3x Mode From DIN Signal High to 90% V <sub>OUT</sub> Steady State	_	1.91	_	ms
tOFF	Shutdown Delay Time	DIN = H- > L		42	_	ms
Isc	Output Short-Circuit Current	—		49	_	mA
Vін	Control Terminal Voltage H	EN1, EN2, DIN Pins	0.8*Vin	—	Vin	V
VIL	Control Terminal Voltage L	EN1, EN2, DIN Pins	0	—	0.2*VIN	V
lih1	Control Terminal Current 1	DIN = 3V	_	—	5	μA
I <sub>IH2</sub>	Control Terminal Current 2	VEN1, VEN2 = 3V, DIN = 3V	_	_	5	μA
Іінз	Control Terminal Current 3	VEN1, VEN2 = 3V, DIN = 0V	_	_	1	μA

## Electrical Characteristics (@T<sub>A</sub> = +25°C, V<sub>IN</sub> = 3.0V, C<sub>PIEZO</sub> = 47nF, f<sub>DIN</sub> = 3.2kHz, unless otherwise specified.)

Notes: 4. It is possible to drive VOUT, VO1 and VO2 to 3x V<sub>DD</sub>. A supply voltage of 4.5V of more should not be used in 3x mode as this will exceed the maximum output voltage rating.

5. When designed under 3x mode, it should be carefully noted that the V<sub>OUT</sub> absolute maximum value should not exceed 13.5V.



## **Application Information**

### Charge Pump Mode Setting

The Charge Pump Mode (CPM) pins EN1 and EN2 are used to set the charge pump into mode 1x V<sub>DD</sub>, 2x V<sub>DD</sub>, 3x V<sub>DD</sub> or they can be used to put the PAM8904E into a forced low current shutdown mode.

DIN	EN1	EN2	MODE
0			Shutdown Mode
1	0	0	Shutdown Mode
1	0	1	1x Mode
1	1	0	2x Mode
1	1	1	3x Mode

V <sub>DD</sub> Range	Mode
1.5V to 4.5V	1x, 2x and 3x
1.5V to 5.5V	1x, 2x

### **Timing Chart and Device Operation**

When one or both of the EN pins are pulled high, the device enters normal operation mode. Refer to the above table for the mode selection. Once the PAM8904E senses a valid signal on the DIN pin, the charge pump will start and provide the desired voltage on the VOUT pin and the output drive VO1 and VO2 start to function after time to<sub>N</sub> which is typically between 470µs and 2s depending on the mode chosen. Once the input signal on DIN is removed, the PAM8904E senses this and waits typically 42ms to ensure the signal has been removed. If there is no further valid signal within the time period to<sub>FF</sub>, the PAM8904E enters into a low current standby mode.

### **Timing Chart**





### Application Information (continued)

### **Output Configuration**

The PAM8904E is able to be configured either in a differential or a single ended configuration.

#### **Short-Circuit Protection**

The PAM8904E has short circuit protection circuitry on the outputs to prevent damage. Once a short circuit is detected on the outputs, the chip will limit the total current to protect the output device. This is not a latched fault; once the short is removed, the normal operation is restored.

#### **Thermal Protection**

If the junction temperature of the PAM8904E exceeds +150°C, the device will enter overtemperature shutdown. The outputs and the charge pump will be switched off. Once the junction temperature cools down to its normal operating condition, the IC will re-start automatically.

### **Ordering Information**



Devi Number	Bashawa	Packing		
Part Number	Package	Qty.	Carrier	
PAM8904EJER	U-QFN3030-16 (Type B)	3,000	Tape & Reel	
PAM8904EJPR	U-QFN3030-12 (Type A)	3,000	Tape & Reel	
PAM8904EGPR	W-QFN2020-12 (Type US)	3,000	Tape & Reel	

# **Marking Information**

U-QFN3030-16 (Type B) / U-QFN3030-12 (Type A)

### (Top View)



P8904E: Product Type Marking Code XXX: Internal Code Y: Year 0 to 9 W: Week: A to Z: 1 to 26 Weeks a to z: 27 to 52 Weeks z Represents 52 and 53 Weeks W-QFN2020-12 (Type US)

#### (Top View)



BM: Product Type Marking Code
XX: Internal Code
W: Week: A to Z: 1 to 26 Weeks a to z: 27 to 52 Weeks z Represents 52 and 53 Weeks



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### (1) Package Type: U-QFN3030-16 (Type B)



U-QFN3030-16						
Туре В						
Dim	Min	Max	Тур			
Α	0.55	0.65	0.60			
A1	0	0.05	0.02			
A3	-	-	0.15			
b	0.18	0.28	0.23			
D	2.95	3.05	3.00			
D2	1.40	1.60	1.50			
Е	2.95	3.05	3.00			
E2	1.40	1.60	1.50			
е	-	-	0.50			
L	0.35	0.45	0.40			
Z	-	-	0.625			
All	All Dimensions in mm					

# (2) Package Type: U-QFN3030-12 (Type A)



	U-QFN3030-12							
	(Type A)							
Dim	Min	Max	Тур					
Α	0.55	0.65	0.60					
A1	0.00	0.05	0.02					
A3	1		0.152					
b	0.20	0.35	0.25					
b1	0.15	0.25	0.20					
D	2.95	3.05	3.00					
D2	1.55	1.75	1.65					
Е	2.95	3.05	3.00					
E2	1.55	1.75	1.65					
е	1		0.50					
h	1		0.25					
L	0.35	0.45	0.40					
k			0.275					
z			0.875					
All	Dimen	sions i	in mm					



# Package Outline Dimensions (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

### (3) Package Type: W-QFN2020-12 (Type US)



W-QFN2020-12 (Type US)					
Dim	Min	Max	Тур		
Α	0.700	0.800	0.750		
A1	0.00	0.050			
A3	0.203REF				
b	0.150	0.250	0.200		
D	1.950	2.050	2.000		
D2	0.850	0.950	0.900		
ш	1.950	2.050	2.000		
E2	0.850 0.950 0.900				
е	0.400 BSC				
e1	0.800 REF				
L	0.250	0.350	0.300		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: U-QFN3030-16 (Type B)



Dimensions	Value (in mm)
С	0.500
G	0.150
G1	0.150
Х	0.350
X1	1.800
Y	0.600
Y1	1.800



## Suggested Pad Layout (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

### (2) Package Type: U-QFN3030-12 (Type A)



Dimensions	Value (in mm)
С	0.500
G	0.175
G1	0.200
Х	0.600
X1	1.350
X2	1.750
Y	0.350
Y1	1.750

(3) Package Type: W-QFN2020-12 (Type US)



Dimensions	Value
	(in mm)
C	0.400
X	0.500
X1	1.050
X2	1.000
X3	2.300
Y	0.250
Y1	1.050
Y2	1.000
Y3	2.300

### **Mechanical Data**

### U-QFN3030-16 (Type B)/U-QFN3030-12 (Type A)

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—NiPdAu Leads, Solderable per MIL-STD-202, Method 208 (4)
- Weight: 0.016 grams (Approximate)

### W-QFN2020-12 (Type US)

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.009 grams (Approximate)



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